



# TS750 THRU TS758

6.0 AMPS. Silicon Rectifiers



Voltage Range  
50 to 800 Volts  
Current  
6.0 Amperes

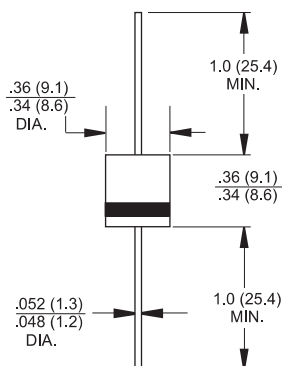
## Features

- ✧ Plastic material used carries Underwriters Laboratory Classification 94V-0
- ✧ High forward current capability
- ✧ Diffused junction
- ✧ High surge current capability
- ✧ High temperature soldering guaranteed: 260°C/10 seconds, 0.375" (9.5mm) lead length, 5lbs. (2.3kg) tension

## Mechanical Data

- ✧ Cases: Molded plastic body
- ✧ Lead: Plated axial leads, solderable per MIL-STD-750, Method 2026
- ✧ Polarity: Color band denotes cathode end
- ✧ Mounting position: Any
- ✧ Weight: 0.07 ounce, 2.1 grams

## P600



Dimensions in inches and (millimeters)

## Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	TS750	TS751	TS752	TS754	TS756	TS758	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	V
Maximum Non-repetitive Peak Reverse Voltage	$V_{BR}$	60	120	240	480	720	1200	V
Maximum Average Forward Rectified Current at $T_A = 60^\circ\text{C}$ , P.C.B. Mounting (Fig. 1) $T_L = 60^\circ\text{C}$ , 0.125" (3.18mm) Lead Length (Fig. 2)	$I_{(AV)}$	6.0 22.0						A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	400						A
Maximum Instantaneous Forward Voltage @ 6.0A @ 100A	$V_F$	0.95 1.25 1.30						V
Maximum DC Reverse Current @ $T_A = 25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A = 100^\circ\text{C}$	$I_R$	5.0 1000						$\mu\text{A}$ $\mu\text{A}$
Typical Junction Capacitance (Note 1)	$C_j$	150						pF
Typical Thermal Resistance (Note 3)	$R_{\theta JA}$ $R_{\theta JL}$	20.0 4.0						$^\circ\text{C/W}$
Operating Junction Temperature Range	$T_J$	-50 to +150						$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	-50 to +150						$^\circ\text{C}$

Notes: 1. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0 Volts

2. Reverse Recovery Test Conditions:  $I_F = 0.5\text{A}$ ,  $I_R = 1.0\text{A}$ ,  $I_{rr} = 0.25\text{A}$

3. Thermal Resistance from Junction to Ambient and from Junction to Lead at .375" (9.5mm) Lead Length P.C.B. Mounted with 1.1 x 1.1" (30 x 30 mm) Copper Pads

## RATINGS AND CHARACTERISTIC CURVES (TS750 THRU TS758)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

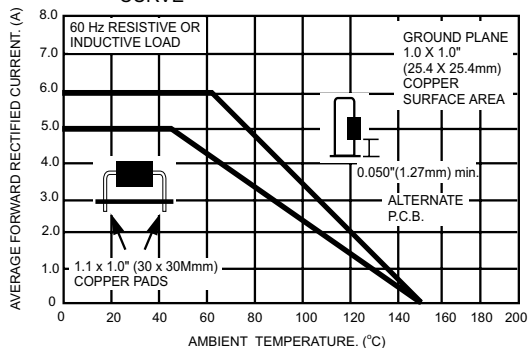


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE

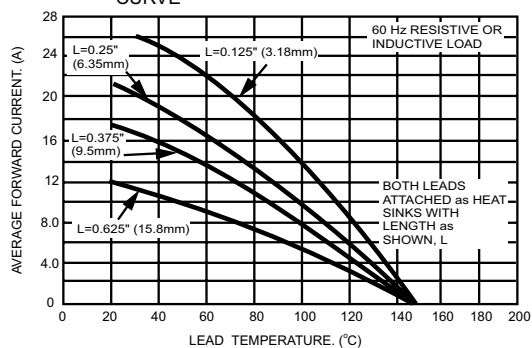


FIG.3- TYPICAL REVERSE CHARACTERISTICS

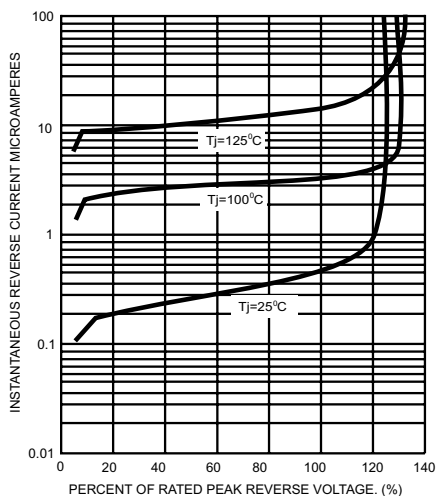


FIG.4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

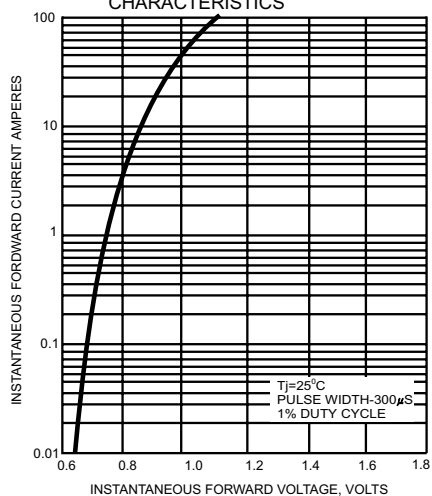


FIG.5- MAXIMUM PEAK FORWARD SURGE CURRENT

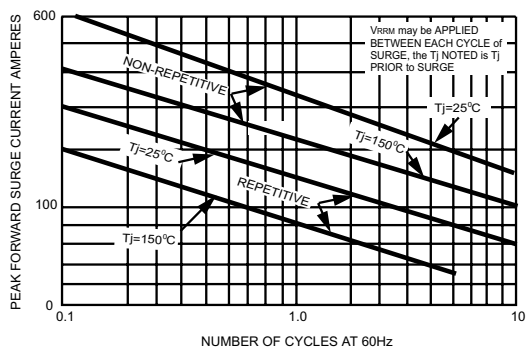


FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE

